# Sharp and Sm ooth B oundaries of Q uantum $H$ all Liquids 

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#### Abstract

W e study the transition betw een shanp and sm ooth density distributions at the edges of $Q$ uantum $H$ all Liquids in the presence of interactions. W e nd that, for strong con ning potentials, the edge of a $=1$ liquid is described by the $Z_{F}=1$ Ferm iLiquid theory, even in the presence of interactions, a consequence of the chiral nature of the system. W hen the edge con ning potential is decreased beyond a point, the edge undergoes a reconstruction and electrons start to deposit a distance 2 m agnetic lengths aw ay from the in itial Q H Liquid. W thin the $H$ artree Fock approxim ation, a new pair of branches of gapless edge excitations is generated after the transition. We show that the transition is controlled by the balance betw een a long-ranged repulsive H artree term and a short-ranged attractive exchange term. Such transition also occurs for $Q$ uantum $D$ ots in the $Q$ uantum $H$ all $R$ egim $e$, and should be observable in resonant tunneling experim ents. E lectron tunneling into the reconstructed edge is also discussed.


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## I. IN TRODUCTION

In Fractionale uantum H all (FQH) states there are no bulk gapless excitations; the only gapless $m$ odes are edge states, which are responsible for non-trivial transport properties at low tem peratures. Edge states arise naturally in real sam ples, as the two dim ensional electron gas (2DEG) is con ned in a nite region. Them anner in which the 2D EG is con ned determ ines the structure of the electronic density on the borders of the sam ple, and rich structures $m$ ay appear. For sm ooth edges, strips of com pressible and incom pressible FQ H statesm ay be form ed [ [ [/2] . The structure of these $s m$ ooth edges have been studied $m$ ainly by focusing on the electronic density distribution at large length scales, where it is reasonable to use a sem i-classical approach [ [ [ 4$]$. This approach consists in assum ing that the electron density $n$ varies slow ly enough, so that one can use bulk values for the intemalenergy $u(n)$, which has cusps for $n$ corresponding to fractional lling factors. An im proved calculation using H artree Fock approxim ation was done in Ref. [5] at nite tem perature, whidh agrees very well w ith the electrostatic calculation [4].

In the opposite extrem e, the electron density varies sharply at the edge, and there is no room for the form ation of incom pressible strips. The sharp edge of the $=1$ state is described by a 1D (chiral) Ferm iLiquid, in which the occupation in the $m$ om entum space has a sharp drop at the Ferm im om entum. This sharp drop in the $m$ om entum space is related to the fast drop of the electron density near the edge.

O ne naturally questions how the sharp edge picture evolves into the sm ooth edge picture as the edge potential becom es sm oother. A s an interacting 1D system, the Ferm iedge of the $=1$ state $m$ ay have the follow ing possible singularities displayed in $F$ igure 1 , such as a Ferm iL iquid singularity, $w$ ith a $Z_{F}=1$ disoontinuity ( F ig. 1a) or a renorm alized $\mathrm{Z}_{\mathrm{F}}<1$ discontinuity ( F ig. 1b), or a Luttinger Liquid singularity ( F ig. 1c). O ne scenario is that the sharp edge and the sm ooth edge are connected by the distributions in $F$ ig. 1b or F ig. 1c. A s the edge potential becom es sm oother, the occupation distributions in Fig. 1b and Fig. 1c also get sm oother. A coording to this picture, the sm ooth edge of the $=1$ state contains one
branch of gapless edge excitations which is described by a renorm alized Ferm iLiquid. The sm oother the edge, the stronger the renom alization. H ow ever, the caloulations presented in this paper suggest a new scenario for som e natural con ning potentials. $W e$ nd that the chiralnature of this one dim ensional system play an im portant role in determ ining the form of the singularity. D ue to the chirality, the $\mathrm{Z}_{\mathrm{F}}=1$ edge is very stable. F ig. 1a correctly describes the edge structure for a range of edge potentials even for interacting electrons. H ow ever, as the edge potential is sm oothened beyond a certain point, the edge undergoes a reconstruction. A pair of edge branches $m$ oving in opposite directions is generated, and the occupation distribution in Fig. 1a changes into the one in Fig. 2, which contains three Ferm ipoints. The occupation $\mathrm{hn}_{\mathrm{k}}$ i has algebraic singularities at these Ferm i points. This new scenario has reøeived som e support from exact calculations on sm all system s.

In this paper we focus on the structure of the electronic occupation density distribution at the boundary of a = liquid in the presence of interactions. W e work with a H ilbert space restricted to the rst Landau level, and in the $m$ ain part of the paper we assum $e$ that the spins are fully polarized. The droplet is con ned by its interaction with an underlying positive background (one way to introduce a con ning potential). The paper is organized as follow s. In section II we introduce the 1D interacting version for the problem, and discuss the im portance of chirality in determ ining the structure of the edge singularity. In section III we present exact num erical results for sm all system $s$, which support the picture that, before a discontinuous transition occurs, the chiraledge system is reasonably well described w ithin the $H$ artree Fock approxim ation. In section $\mathbb{I V}$ we study the e ects of this transition for $Q$ uantum $D$ ots, including possible experim entally observable e ects. F inally, in section V we investigate the consequences of the transition on the dynam ics ofedge excitations, and in section V I the consequences to electron tunneling into the reconstructed edges.
II. THE 1D $\mathbb{N} T E R A C T \mathbb{N G}$ M ODELAND CONSEQUENCESOFCH IRALITY

A system of interacting particles in a $2-D$ Q H droplet can be mapped into a one dim ensional problem by enum erating the single particle wavefunctions of the rst Landau level. The H am ittonian of the interacting theory is

$$
\begin{equation*}
\mathrm{H}=\frac{\mathrm{x}}{; 0} \quad ; \mathrm{C}^{\mathrm{y}} \mathrm{C}_{0}+\frac{\mathrm{x}}{1 ; 2 ; 3 ; 4} \mathrm{~V}_{1 ; 2 ; 3 ; 4} \mathrm{C}_{1} \mathrm{C}_{2} \mathrm{C}_{3}^{\mathrm{y}} \mathrm{C}_{4} ; \tag{1}
\end{equation*}
$$

where

$$
\begin{aligned}
& \text { z } \\
& ; 0=\mathrm{dx}_{1}^{2} \mathrm{dx}_{2}^{2} \quad\left(\mathrm{x}_{1}\right) \mathrm{V}\left(\mathrm{x}_{1} \quad \mathrm{x}_{2} \mathrm{~J}\right) \quad\left(\mathrm{x}_{2}\right) \quad 0\left(\mathrm{x}_{2}\right) \\
& V_{1 ; 2 ; 3 ; 4}=\frac{1}{2}^{2} d x_{1}^{2} d x_{2}^{2} \quad\left(x_{1}\right) \quad{ }_{2}\left(x_{1}\right) V\left(\dot{x}_{1} \quad x_{2}\right)_{3}\left(x_{2}\right) \quad{ }_{4}\left(x_{2}\right):
\end{aligned}
$$

The dispersion ; 0 is determ ined by a background charge $(x)$, which we use to control the con ning potential. The 's are the single particle wavefunctions, labeled by the quantum number . For exam ple, in the sym $m$ etric gauge, stands for the angular $m$ om entum
 we work in units of m agnetic length $l_{B}=1$ ). The wavepacket $m$ is centered in a circle of radius $R={ }^{\mathrm{P}} \overline{2 \mathrm{~m}}$. In the Landau gauge, denotes the linear m om entum in the x direction $k_{x}$, w th $k_{x}(x ; y)=\frac{1}{\left(-C_{L}\right)^{1=2}} e^{i k_{x} x} e^{\left(y k_{x}\right)^{2}=2}$, and the wavepacket $k_{x}$ is centered at $y=k_{x}$ ( $L$ is the size of a system sub ject to periodic boundary conditions) .

Let us consider for now badkgrounds $(x)$ that are invariant under œertain sym $m$ etry transform ations, such as rotations (ifw e are studying a circular droplet, using the sym m etric gauge) or translations along the x direction (ifw e are studying a long strip, using the Landau gauge). In this case we have $; 0=\quad ; 0$. Im purities break such sym $m$ etries, and their e ect will be considered later in the paper. Because the interaction $V$ ( $\mathbf{x}_{1} \quad x_{2}$ ) depends only on the distance between $x_{1}$ and $x_{1}$, it is also invariant under these sym $m$ etries, and thus we can rew rite the H am iltonian as

It is this 1 D interacting m odel that w ill be the basis of our study of the $=1$ droplet. The question we want to address is how to determ ine the ground state occupation num ber hd ${ }^{y} \mathrm{C}$ i for this theory.

W thout loss of generality, let us focus now on the problem of a strip w ith length $L$ and periodic boundary conditions (equivalently, a cylinder of circum ference L), using the Landau gauge. The QH F luid lies on the surface of the cylinder, betw een its left (L) and right $(R)$ boundaries (see Fig. 3).

In a typical1D interacting theory we have non Ferm iLiquid behavior; the Ferm idiscontinuity is destroyed by the interactions, and the system is better described as a Luttinger Liquid. N otice, how ever, that the Ham iltonian in Eq. (2) has a peculiar di erence from the usual1D H am iltonian of an interacting system in the sense that the e ective scattering potential $V$ depends not only in the $m$ om entum transfered, but also in the $m$ om entum con guration (i.e., and ${ }^{9}$ ) of the scattered particles. The Luttinger Liquid behavior is caused by the coupling between particle-hole excitations in the two distinct Ferm ipoints. Now, for our system described in Eq. (2), the two Ferm ipoints correspond to $L$ and $R$, at the two boundaries of our droplet. These two points are spatially separated, and the $m$ atrix elem ents for coupled particlehole excitations near these points should go to zero as the distance betw een the boundaries is increased. In the lim it of in nite separation, the two edges are decoupled, and we can describe the system as containing two di erent types of ferm ions, R and L , w th one Ferm ipoint each. M ore precisely, we can describe the particles as being in a D irac sea that is led as we m ove inw ards to the bulk. Indeed, in topologies such as a sim ply connected droplet, like a disk, we only have one boundary, and the D irac sea description is exact. Such theories fallw ithin what we call \C hiral Luttinger Liquids" .

The 1D chiraltheory has a specialproperty that the occupation distribution of the ground state can have a Ferm idiscontinuity (Ferm iLiquid) even in the presence of interactions. In fact, for certain values of interaction strength and single particle dispersion, the ground state $m$ ay have a perfect Ferm idistribution $w$ th $Z_{F}=1!T h i s$ is because the $m$ om entum occupation $w$ ith $Z_{F}=1$ is always an eigenstate of the interacting $H$ am iltonian (月) in the
lim it of in nitely separated edges. This is easier seen in the lled D irac sea description of the $L$ and $R$ ferm ions. Take, for exam ple, the $R$ branch, for which the unique $m$ in $m u m$ totalm om entum eigenstate is the one that has all single particle levels to the left of the edge occupied. Because totalm om entum comm utes $w$ ith the $H$ am iltonian, and this state is the only one with m inim um total m om entum, it m ust also be an eigenstate of energy, possibly the ground state for som e edge potential. N otice that the occupation distribution of this state corresponds exactly to a $Z_{F}=1$ Ferm iLiquid occupation. O ne should contrast this case w th a non-chiral 1D system, where clearly the Ferm igas distribution is an eigenstate of zero totalm om entum, but it is not the only one, and thus not necessarily an eigenstate of energy. A gain, chirality plays a key role.

The next step is to understand how the occupation distribution evolves as we sm oothen the con ning potential. O ne way to assemble a sharp distribution is by sim ply laying the electron gas on top of a sim ilarly shanp positively charged background, and one way to try to destroy this sharp distribution is to sm oothen the positive background. N otioe that the perturbation we include by changing the background is not in the form of an additional interaction between the particles, but of a change in the one particle dispersion . We w ill show that the occupation distribution has the tendency to rem ain shapp, due to a balance between a repulsive long range H artree term and an attractive short range Fock term, and also due to the special stability of the $Z_{F}=1$ chiral Ferm i Liquid. The shanp distribution eventually becom es unstable, and the Ferm i surface is destroyed, as a lum p of particles detach and form two m ore edges which destroy the chirality. W e w ill show that the $H$ artree $F$ ock approxim ation seem s to contain the relevant ingredients to describe this transition.
III.EXACT RESULTS FOR SMALL SYSTEMS

In the Landau gauge, the dispersion due to the badkground charge, and the $m$ atrix elem ents V in Eq . (2) for the C oulom b interaction are given, respectively, by:

$$
\begin{equation*}
k=\underline{e}^{2^{Z}}{ }_{1} d y^{0} \quad\left(y^{0}\right)^{Z_{1}} d y \frac{e^{(y} p^{\left.k+y^{0}\right)^{2}}}{p-} \ln y^{2} \tag{3}
\end{equation*}
$$

and

$$
\begin{equation*}
V(q ; k)=\frac{e^{2}}{\frac{1}{L} e^{P} \bar{q}^{2}=2}{ }_{1}^{2} d y e^{(y} k^{2}=2 K_{0}(q y) \tag{4}
\end{equation*}
$$

where $e$ is the electron charge, is the dielectric constant, $q$ is the $m$ om entum transfer ( in Eq. (目) ), $k=k \quad k^{0}$, is the positive background density, and $K_{0}$ is a m odi ed Bessel function. N otice that $e^{2}=I$ (or $e^{2}=$, as we use units of $I=1$ ) is the natural energy scale in the problem. In particular, the $H$ artree Fock e ective two body potential between two particles $w$ th $m$ om enta $k_{1}$ and $k_{2}$ is given by

$$
\mathrm{V}_{\mathrm{HF}}\left(\mathrm{k}_{1} ; \mathrm{k}_{2}\right)=\mathrm{V}_{\mathrm{H}}\left(\begin{array}{ll}
\mathrm{k}_{1} & \left.k_{2} j\right)+\mathrm{V}_{\mathrm{ex}}\left(\begin{array}{ll}
\mathrm{k}_{1} & k_{2}
\end{array}\right), \tag{5}
\end{array}\right.
$$

where the $H$ artree and exchange term $s$ are obtained from Eq. (4) by setting $q!0, k=$ $k_{1} \quad k_{r}$ and $q=k_{1} \quad k_{1}, k=0$ respectively ( $w$ ith a factor of 1 for the exchange):

$$
\begin{align*}
& V_{H}\left(k_{1} \quad k_{2} j\right)=\frac{1}{2 L} e^{2}{ }_{1}^{Z} d y \frac{e^{\left(y k_{1}+k_{2}\right)^{2}=2}}{P} \frac{\ln y^{2}}{2}  \tag{6}\\
& V_{\text {ex }}\left(k_{1} \quad k_{2} j\right)=\frac{1}{2 L} \frac{e^{2}}{} e^{\left(\frac{k_{1} k_{2}}{2}\right)^{2}} K_{0}\left(\frac{k_{1}}{2}\right)^{2}:
\end{align*}
$$

We have subtract a logarithm ic divergence from the H artree term ( ln qiq! o), that is independent of $k_{1}$ and $k_{2}$, and thus sim ply contributes to a constant in the energy. The $H$ artree contribution to the e ective tw o body potential, $\mathrm{V}_{\mathrm{H}}$, is repulsive and long-ranged, whereas the one from exchange, $\mathrm{V}_{\text {ex }}$, is attractive and short-ranged. W ew ill show that it is a balance betw een these tw o e ective interactions that controls the short length scale behavior of the density distribution.

W ew ill proceed by rst presenting exact num erical results for a sm all system, and then using these results to justify a picture that the short length scale behavior of the density distribution is controlled by the H artree Fock term s.

W e study the edge structure of a system that we divide into \edge" and \bulk" electrons (See Fig. 4). W e consider just one edge, say, the R edge, and assum e the \bulk" extends to
in nity in the opposite direction. The occupation of the \bulk" levels is xed to be 1. D oing so, we can concentrate all the com putations on the \edge", as the e ect of $\backslash$ bulk " electrons is sim ply reduced to a contribution to the one particle dispersion of the \edge" electrons. Such division presents no harm, as long as the edge excitations under consideration do not change the $\backslash$ bulk" occupation.

C onsider a strip geom etry w ith $L=20 \mathrm{~b}$ and periodic boundary conditions (cylinder). The ledge" is com posed of 10 electrons in 20 single particle states. W e start with a shanp background, and sm oothen it by changing the width $w$ in which the density drops from the bulk value ( $=1=2$, for $=1$ ) to zero (see $F$ ig. 5). The \bulk" electrons contribute to an additionalterm in the dispersion. The e ect of adding a variation in the positive charge density over a length scale $w$ can be thought of as sim ply superim posing a dipole to the e ective edge potential for a shanp edge, as show n in Fig. 5.

Fig. 6 displays the energy levels for di erent totalm om entum $K$ of the edge electrons (the sites, num bered from 1 to 20 , are assigned $k=0$ to 19). Forw $<8 l_{B}$ the ground state has $K=45$, i.e., all the electrons are packed up to one side and the edge is described by the $Z_{F}=1$ Fem i liquid. For $w=9 b$ the ground state is no longer the sharp con guration $w$ ith $m$ inim um $K=45$, but has $m$ oved to a con guration $w$ ith $K=60$ (see F ig. 7). The occupation num ber distribution is show $n$ in $F$ ig. 8 forw $=9$ and $10 l_{B} . N$ otice the form ation of a lum $p$ of electrons distant 2 F from the bulk (for $\mathrm{L}=20, \mathrm{k}=1$ corresponds to a distance $2=\mathrm{L} \quad 0: 314 \mathrm{~g})$.

The exact calculation for a sm all system s to indicate that the shanp edge is robust against the sm oothening of the background charge, up to a point where there is a transition, and the density redistributes. We will show that the robustness of the shanp edge is a consequence of the attractive exchange, that tents to keep the edge packed. Eventually, as the strength of the dipole resulting from the sm oothening of the background is increased, the short range attraction due to exchange can no longer sustain the edge sharp, and a lum $p$ of the electrons splits and form sa \puddle" near them inim um of the e ective potentialseen by the Q H Liquid. Let's ilhustrate the point above by calculating the e ective single particle
energy w ithin the $H$ artree Fock approxim ation for the distribution that has occupied levels for all negative $m$ om enta, i.e., a shanp $R$ edge (we have centered the coordinate system on the edge).

$$
\begin{equation*}
(k)={ }_{k}+{ }_{\mathrm{H}}(\mathrm{k})+\mathrm{ex}(\mathrm{k}) \text {; } \tag{7}
\end{equation*}
$$

where

$$
\begin{aligned}
& k={\frac{e^{2}}{}}_{1}^{Z_{1}} d y^{0} \quad\left(y^{0}\right)^{Z} d y \frac{e^{\left(y y^{\left.k+y^{0}\right)^{2}}\right.}}{p-} \ln y^{2} \\
& \text { н }(k)=\underline{e}^{Z^{Z}}{\frac{d k^{0}}{2}}_{1}^{2} d y \frac{e^{\left(y{ }^{\left.k+k^{0}\right)^{2}=2}\right.}}{\overline{2}} \ln y^{2} \\
& \text { ex }(k)={\frac{e^{2}}{}}_{1}^{2} \frac{d k^{0}}{2} e^{\left(\frac{k k^{0}}{2}\right)^{2}} K_{0} \quad\left(\frac{k \quad k^{0}}{2}\right)^{2} \text { : }
\end{aligned}
$$

O ne should notioe that the electronic occupation num ber $n_{k}=h g_{k}^{y} q_{k} i d i$ ers from the electronic charge density $n(y)=h c^{y}(y) c(y) i$. The later is obtained from the form er by a convolution w th a G aussian of variance ${ }^{2}=1=2$ (the single level charge distribution). W th this in $m$ ind, one can show that the background density that cancels the electronic charge density is exactly the one that $m$ akes ${ }_{k}+_{H}(k)=0$, as it should be expect. A shanp badkground charge distribution as shown in Fig. 5 m akes a sharp electronic occupation distribution even $m$ ore stable, as we have an extra dipole term, resulting from the di erence between a sharp positive charge background and the electronic charge density of a sharp occupation distribution, and which favors the levels $w$ ith negative $k$ to rem ain occupied.

As we change the background con guration, we alter the one particle dispersion $k$. For the stability of this edge it is necessary that the e ective single particle energy of any unoccupied level be higher than the one of any occupied level. Fig. 9 show s the e ective single particle energy for unoccupied levels for di erent values of the param eter $w$, which $m$ easures the $w$ idth which it takes the badkground to decrease from its bulk value to zero. The potential obtained forw $=0 l_{B}$ is prim arily due to the exchange term, which stabilizes a sharp edge. The exchange potential is short ranged, reaching zero within $\quad 1: 5 \quad 2 \mathrm{~B}$; the overshoot for $w=0 l_{B}$ is due to the dipole which results from the di erence between
a sharp positive charge background and the electronic charge density of a sharp occupation distribution, asm entioned previously, whose contribution decays to zero as $1=\mathrm{j}$ j jfor large k j . For w 11 g the condition for stability is violated (the higher value for the $w$ that $m$ arks the transition, as com pared to the sm allsystem result, can be regarded as due to a nite size e ect, to the $H$ artree $F$ ock approxim ation, or to both). It is then $m$ ore advantageous to $m$ ove electrons to the minim um (k) locations. A sim ple picture is that particles start to escape from the sharp edge and start to deposit at a distance of order 2 z aw ay from the initial boundary. This separated lum p brings in two new boundaries into the problem. These new boundaries break our previous chiral geom etry, as we now have three Ferm ipoints nitely separated. The three Ferm ipoints describe two right-m oving branches and one left-m oving branch of edge excitations. From this point on one should expect that the interactions w ill destroy the Ferm i Liquid singularities, and we will have three Luttinger singularities.

N otioe that we said the necessary condition for the stability of the sharp edge is that (k) be larger for unoccupied states than for occupied states. But we have not yet argued it is su cient. It is possible that even if this condition is satis ed one can have a ground state for the interacting problem di erent than the sharp edge, as the energy could be lowered by rearranging $m$ any particles. $W$ orse, it is possible that the hopping term $s$, whidh couple di erent states in con guration space (and are not included within H artree Fock), would com pletely modify the picture. In particular, the Hartree Fock approxim ation does not allow the distributions in $F$ ig. 1b and $F$ ig. 1c. Therefore, we cannot use the $H$ artree $F o c k$ calculation alone to judge which of the distributions in Fig. 1 and Fig. 2 is realized after the transition. H ow ever, the exact diagonalization results for sm all system $s$ that we have presented support the picture described in Fig. 2. This suggests the transition is mainly controlled by H artree Fock tem S, and that the conclusions depicted from the single particle potentialobtained w ithin H artree Fock seem to be qualitatively correct. C ertainly we cannot rule out the possibility that $F$ ig. 1 b and F ig. 1cm ight be realized for som e other interaction and edge potential.

To nalize this section, we present in F ig. 10 the spectrum and occupation num bers
calculated for the sm all system w th $w=10 l_{B}$, but now $w$ ithin the $H$ artree Fock approxim ation (the hopping or o -diagonal elem ents were suppressed). C om pare the spectrum to the exact diagonalization for $\mathrm{w}=10 \mathrm{l}_{B}$ displayed in F ig. 7. The occupation num bers in the $H$ artree $F$ ock approxim ation suggest the separation of part of the density from the $m$ ain uid, and the appearance of tw $o m$ ore singularities. The hopping elem ents would take charge in redistributing the density, m odifying the form of the singularity.
IV.THE EDGERECONSTRUCTION FOR QUANTUM DOTS

The e ect we describe in this paper is not particular to large system s. In fact, the exact results for sm all system $s$, which we used to support the $H$ artree $F$ ock picture, directly indicate that the transition occurs for nite system s . The edge density redistribution is a consequence of the balance betw een the con ning potential, the repulsive H artree term, and the short-ranged exchange, all of these present regardless of the size of the system .

Q uantum D ots are innately interesting system sfor observing this transition. To begin w ith, because the num ber of electrons is sm all, the redistribution $w$ ill involve a substantial part of the total num ber of particles in the dot, which can then be considered not sim ply an edge e ect, but, in a way, a bulk e ect as well. Secondly, experin ents on resonant tunneling into $Q$ uantum $D$ ots in the $F Q H$ regim e should be sensitive to a transition involving a redistribution of the particle density, both because the energies of adding one electron to the dot on both sides of the transition should di er (which can be m easured by the position of the resonant peaks), and because a change in the size of the dot will change the coupling to the probe leads as well. Third, the transition can be driven by altering the con ning potential, either changing the voltage on a back-gate, or changing the magnetic eld (which varies the radii of the orbits, and consequently the potential seen by each orbit).

In this section we study som e of the consequences of the transition as applied to $Q$ uantum D ots. We study system s w th total number of particles up to $\mathrm{N}_{\mathrm{p}}=70$. W e will use only the $H$ artree Fock $m$ atrix elem ents, because both the system is not sm all enough for
exact diagonalization, and the $H$ artree Fock approxim ation seem ed to contain the essential elem ents to describe the transition.

The energy eigenstates of the H am iltonian in Eq. ( 2 ) are also eigenstates of total m o$m$ entum. The true ground state is a supenposition of di erent occupation num ber states in Fock space, all of them with the sam e totalm om entum. W e will call hopping elem ents the term s in the H am iltonian that couple di erent states in Fock space. T he H artree and Fock term scouple a con guration in Fock space to itself. W ithin H artree Fock, i.e., neglecting the hopping term s in the H am iltonian, any occupation num ber state is an energy eigenstate. $F$ inding the ground state is then equivalent to determ ining the con guration of particles that $m$ in ím izes a classical energy function. $N$ otioe that within $H$ artree $F o c k$ all he ${ }^{y} \mathrm{c} i$ are equal to either 0 or 1 .
$W$ e focus on a disk geom etry, which is $m$ ore appropriate for describing a dot. The single particle states are labelled by the angular $m$ om entum quantum number. The $m$ atrix elem ents are given by

$$
\begin{equation*}
\mathrm{V}_{\mathrm{m} 1, \mathrm{~m} 2, \mathrm{~m} 3, \mathrm{~m} 4}=\mathrm{mm} 1 \mathrm{~m} 3 \hat{\mathrm{~F}} \mathrm{~F} \mathrm{jn} 2 \mathrm{~m} 4 \mathrm{i} ; \tag{8}
\end{equation*}
$$

$w$ here the state $j n m{ }_{i}$ stands for a particle in the level labelled by $m$, and another in the
 $m$ atrix elem ents in the classical energy function that couple states $m$ and $m^{0}$ are obtained from the H artree and Fock term s:

$$
\begin{equation*}
\mathrm{V}_{\mathrm{m}, \mathrm{~m} 0}^{\mathrm{HF}}=\mathrm{V}_{\mathrm{m}, \mathrm{~m}, \mathrm{~m} 0, \mathrm{~m}} 0 \quad \mathrm{~V}_{\mathrm{m}} 0_{m, m, m} 0: \tag{9}
\end{equation*}
$$

To obtain these coe cients it is easier to work in a basis in which $\hat{V}$ is diagonal. The j; ni basis, in which $h z_{1} ; z_{2} \eta ; n i=p^{1}=\frac{z^{n} z^{1}}{n!1!} e^{\frac{z_{+}+f^{2}+j z f^{2}}{2}}$, where $z=\frac{z_{1}}{\frac{z_{2}}{2}}$, is such that $h l ; n j \hat{F} \eta^{0} ; n^{0} i=V(1) \quad 1 ; 1^{1} n ; n^{0}$. For the Coulomb interaction we have

$$
\begin{align*}
& =\frac{e^{2}}{m} \frac{1}{4} \frac{(1+1=2)}{(1+1)}: \tag{10}
\end{align*}
$$

The H artree and exchange term s are obtained, respectively, using
and

The con ning potential is assum ed to be parabolic, $(r)=\frac{1}{2} k r^{2}$, with $r$ the distance from the center of the dot, and $k$ the strength of the con ning potential. It is convenient to $w$ rite $k=0 \frac{e^{2}}{b} l_{B}^{2}$, so that 0 is a dim ensionless param eter, $m$ aintaining $e^{2}=I$ and $l_{B}$ as our, respectively, energy and length units. T he single particle dispersion is given by

$$
\begin{align*}
m & =\frac{1}{2} 0 \frac{e^{2}}{z} \quad \frac{d z^{2}}{z \dot{z}} \frac{\dot{z}^{\dot{z} \mathcal{f}^{m}}}{m!} e^{\dot{z} \mathcal{f}}  \tag{13}\\
& =0 \frac{e^{2}}{z} \frac{(m+2)}{(m+1)}=0 \frac{e^{2}}{z}(m+1):
\end{align*}
$$

The energy function that $m$ ust be $m$ in $m$ ized is
where the $n_{m}$ 's are 0 or 1 , constrained to ${ }^{P} n_{m}=N_{p}$, the total num ber of particles. $W e$ obtained num erically $\mathrm{V}_{\mathrm{m}}^{\mathrm{H}} \mathrm{m}$. for the rst 80 levels ( $0 \quad \mathrm{~m} ; \mathrm{m}^{0} \quad$ 79), and searched for the m in m um ofe fordi erent values ofn $\mathrm{p}_{\mathrm{p}}$ and $0 . \mathrm{We}$ nd that, depending on these param eters, the $m$ inim um energy con guration $s w$ itches from a com pacted to a separated droplet.

In $F$ ig. 11 we display the occupation of the orbits as function of ofor $\mathrm{N}_{\mathrm{p}}=60$ (occupied orbits are displayed in black, and unoccupied ones in white). For strong con ning potentials the occupied levels are the ones $w$ th $m$ inim um angular $m$ om entum. As the con ning strength is decreased, there is a transition, and unoccupied levels inside the dot appear. A fter the transition, hopping elem ents becom e im portant, and take charge in redistributing the occupation, which can then have partially lled levels. Fig. 12 displays the onbital occupation for $x e d$, 0 w th $N_{p}$ varying from 70 to 30 electrons, where there is also a transition, $w$ th a separated droplet for sm aller system $s$.

W e would like to point out that the exchange term is of key im portance in order to have a com pacted dot solution. N otioe that we have assum ed that occupation is non-zero only for the rst Landau level, and that the spins are fully polarized. O ne could argue that these assum ptions alone can lead to a com pacted drop, as a strong enough con ning potential can alw ays be chosen such that the ground state is the minim um total angular m om entum solution even if one take only the repulsive H artree term. This would be possible because the particles w ould be squeezed to the center, w ithout being able to occupy higher Landau levels, or ip spin (see Fig. 13, where we repeat the caloulation for Fig. 11 w thout the exchange term ). In reality, as we increase the con ning potential, there are two $m$ echanism $s$ which tend to low er the totalenergy of the dot, one by com pacting the particles to the low angular $m$ om entum orbits in the rst Landau level, with polarized spins, and the other by m oving particles to a higher Landau level or opposite spin polarization state. By increasing the con ning potentialwe enhance both of these e ects. Therefore, in order to have a $=1$ com pacted dot we m ust have a w indow of o that allow s totally packed dots $w$ th no higher Landau level occupation. It is here that exchange com es in play, providing an attractive interaction that low ers the bound on 0 to have a com pacted dot, which opens that $w$ indow .

The ideas above can be expressed quantitatively. The low er bound on 0 , i.e., the $m$ inim um con ning strength necessary to keep an $\mathrm{N}_{\mathrm{p}}$-particle dot com pacted, can be obtained as follows. W ithin the H artree approxim ation, ${ }_{0}^{m}$ in is obtained from the condition that the net electric eld on the edge of the dot due to the electrons just balances the eld due to the con ning potential. The radial eld due to the electrons diverges logarithm icaly, $E_{r} / \frac{e}{p_{B}} \ln \left(R={ }_{c}\right)$, where $R$ is the radius of the droplet, and $c$ is an ultraviolet cut-o
 ${ }_{0}^{m}$ in $/ N_{p}{ }^{1=2} \ln \left(\frac{N_{p}}{{ }_{c}^{2}=22_{B}^{2}}\right)$. Indeed, this dependence of 0 on $N_{p}$ ts very well the num erical results obtained when the exchange term is om itted (H artree approxim ation), where we nd ${ }_{0}^{m} \quad 0: 118 N_{p}{ }^{1=2} \ln \left(\frac{N_{p}}{0: 16}\right)(s e \mathrm{~F}$ ig. 14a). We nd that a sim ilar function dependance on $N_{p}$ reasonably ts the results obtained $w$ ithin $H$ artree Fock, $w$ ith $\int_{0}^{m}$ in $0: 083 N_{p}{ }^{1=2} \ln \left(\frac{N_{p}}{0: 21}\right)$ for our range of $\mathrm{N}_{\mathrm{p}}$ ( F ig. 14b). N otice that the attractive exchange term has the tendency
to keep the dot com pated, low ering the value of ${ }_{0}^{m}$ in .
The upper bound on ocan be obtained by estim ating the energy decrease of $m$ oving one particle from the edge to the center. T he electrostatic energy of a disk of radius $R$ and density $0=\frac{e}{2 \frac{l^{2}}{b}}$ is $E_{\text {disk }}=\frac{e^{2}}{b} \frac{2}{3}\left(R=l_{B}\right)^{3}$, which gives an estim ate for the electrostatic energy of adding one electron to the edge of the dot of $\mathrm{E}_{\text {edge }}=\frac{e^{2}}{\xi} \frac{2^{\mathrm{p}} 2}{}{ }^{q} \overline{N_{p}}$. The electrostatic energy cost of adding an electron to the center of the disk is $E_{\text {center }}=\frac{e^{2}}{\mathrm{P}} \bar{q}^{\mathrm{q}} \overline{\mathrm{N}_{\mathrm{p}}}$. The total decrease in energy of $m$ oving one particle from the edge to the center is $E=\frac{e^{2}}{b} \quad{ }_{0} N_{p} \quad{ }_{2}^{p} \overline{2}^{q} \overline{N_{p}}$, which has to be $<h!c$ (or $<E_{z \text { eem an }}$ ) if we want to have occupation solely in the rst Landau level (or with polarized spins). So we nd
 the cyclotron (or Zeem an) and Coulomb energies. The condition for a com pacted dot is
 for reasonable values of $B$ and $N_{p}$ in a dot, the term $N_{p}{ }^{1=2}$ in $\int_{0}^{m a x}$ is the dom inant one, which constrains the maxim um possible $N_{p}$ to the one that $m$ akes ${ }_{0}^{m}{ }_{0}^{\text {in }}{ }_{0}^{m a x}$, which gives $N_{p}^{m}$ ax 106. If we use the value for ${ }_{0}^{m \text { in }}$ given by the $H$ artree term alone we nd $N_{p}^{m}$ ax $\quad$ 12. A though these values are rough estim ates, they should $m$ ake it clear that the attractive exchange term plays a major role in opening up a window in oforwhich there is a com pacted dot solution.

W e have also perform ed the $H$ artree $F$ ock calculation for spin $1 / 2$ electrons $w$ ith Zeem an energy $E_{z \text { eem an }}!0_{+}$(sim ply to break the degeneracy betw een the two spin polarized congurations). For large con ning potentials, both spin up and down electrons form com pact droplets of lling fraction $=1$. H ow ever the droplet of, say, spin dow n electrons is sm aller, and the electrons near the edge form a ferrom agnetic state as pointed out in $R$ ef. [G]. A swe decrease 0 , the separation betw een the spin-up edge and the spin-dow $n$ edge increases. At even sm aller othe spin-dow $n$ electrons non-longer form a com pact droplet whidh $m$ aybe a sign ofFQ H states. As o decreases below s $0: 53 \mathrm{~N}_{\mathrm{p}}{ }^{1=2}+0: 49 \mathrm{~N}_{\mathrm{p}}{ }^{1}$, all the electrons are spin polarized (the ooe cient in $N_{p}{ }^{1=2}$ is approxim atly the sam e obtained from the electro-
static consideration, and the one in $N_{p}{ }^{1}$ shows the tendency of exchange to align spins as an e ective Zeem an energy). Thus for $0_{0}^{m}<0<$ in $^{\text {in }}$, the electrons form a spin polarized com pact droplet. The exchange term tends to align the spins, increasing further the size of the window of o's such that the drop is com pact.

The next question is how to experim entally obtain a value for o that falls within the w indow above. In order to m ake the connection to real sam ples, we use the parabolic con ning potential in Ref. 7]. There they use $V_{\text {ext }}(r)=\frac{1}{2} m \quad!^{2} r^{2}$, with $m$ the e ective electron $m$ ass in $G a A s$, and $h!=1: 6 \mathrm{~m} \mathrm{eV}$ for the particular device. The relation between our dim ensionless o(or altematively, given in units of $\frac{e^{2}}{B}=1$ and $l_{B}=1$ ) to this con ning potential is obtained by equating $0 \frac{e^{2}}{B} l_{B}^{2}$ to $m!^{2}$, which gives $0=\frac{(h!)^{2}}{\left(e^{2}=\xi\right)(h!c)}$, or 0 $0: 376 B^{3=2}$, B in Tesla. For $N_{p}=40$, for exam ple, we nd that $B=2: 5 \mathrm{~T}$ willyield a value of 0 in the allowed $w$ indow, so that the dot occupation $w$ ill be the one of a com pacted
$=1$ droplet. A s we increase B beyond 3.1T the edge w ill undergo a reconstruction.
W e now tum into the possibility of probing experim entally the transition between a com pacted and an expanded dot. In order to $m$ ake a clear connection between this expansion e ect and experim entally observable quantities, we describe below the im plications of the e ect to tunneling experim ents into $Q$ uantum $D$ ots. In resonant tunneling experim ents, the energy di erence betw een the ground states of an $N+1$ and $N$ electron system, $(\mathbb{N})$, can be probed by tunneling in and out of the dot a single electron at a tim e , when the Ferm ilevel of the electrodes becom e resonant w ith the quantum level of the dot 图;10]. By follow ing a peak, the dependence of the chem ical potential on the $m$ agnetic eld can be observed. In $F$ ig. 15 we calculated, w ithin the $H$ artree $F$ ock approxim ation, this dependence of the chem ical potential (in meV ) on B (in T ) for dots w th $\mathrm{N}_{\mathrm{p}}$ from 35 to 38 . The $\backslash$ saw tooth" for $B<2: 5 \mathrm{~T}$ corresponds to spin dow electrons being ipped and $m$ oved from the center to the edge of the dot. The region between roughly 2.5 T and 3 T is the w indow ofm agnetic elds forwhich the electrons form a com pact $=1$ droplet. $T$ he $\backslash$ dislocation" near $B=3 T$ corresponds to the reconstruction of the electron num ber occupation, $m$ arking the transition from the com pacted to the expanded con guration.

In addition to this anom aly in the peak position vs. B, the expansion of the size of the dot will also increase its coupling to the probing leads, as this coupling depends on the distance between leads and island. The tunneling current should then increase for an expanded dot. In Fig. 16 we show the dependence of the size of the droplet ( $m$ easured as the radius of the orbit of the outm ost electron) on 0 and on the num ber of particles $N_{p}$ in the dot. In Fig. 16a we show the size of a 60 electron droplet as a function of 0 , and in Fig. 16b we xed the value of 0 and varied the num ber of electrons from 40 to 70 . The e ect on the am plitute of the resonant peak, together w ith the anom aly in the peak position, should be a signature that a transition is indeed occurring in the occupation density of the Q uantum D ot.

## V.THEEDGEMODESAFTERTHETRANSITION

A s we have seen in the previous sections, after sm oothening the edge potentialenough, a transition takes place, and the Ferm iLiquid occupation density gives w ay to a m ore com plex state. In term s of the electronic occupation distribution, the new state looks as if electrons start to deposit a certain distance aw ay from the bulk of the Q H Liquid. The Q H \puddle" that is form ed, as $m$ entioned above, brings in two $m$ ore boundaries for each edge, and we then have three singularities. The interactions take charge in destroying the Ferm iLiquid discontinuity, as the three singularities are nitely separated.

These three singularities can be related to three branches of gapless m odes, which correspond to particle-hole excitations near each of the singularities. An intuitive way to visualize the three branches is by considering the occupation num ber after the transition sim ply w ithin H artree Fock, which would look as in Fig. 17. There, the three edges are clearly identi ed. C orrelations destroy the Ferm i discontinuities, but we will still have the three Luttinger Liquid singularities at the three Ferm i points. N otioe that the pair of branches that is added always have opposite chirality. A $n$ edge that had one right-m oving branch before the transition, for exam ple, w ill have tw o right-m oving branches and one left-m oving
branch. All these three branches are strongly coupled. O ne clear experim ental consequence of now having one branch $m$ oving in the opposite direction (the one left-m oving branch in the originally right-m oving edge, for exam ple) is that one could probe such excitations, where originally there was none. W e will show, however, that the presence of im purities localize two of the three branches, and such back-propagating $m$ odes cannot be observed beyond the localization length.

W e will use the bosonized description of the edge states in the FQ H regim e presented in Ref. [11], and which we sum $m$ arize below for our particular case of $=1$. Let ${ }_{\mathrm{R} ; \mathrm{L}}$ be two elds, described by the Lagrangian density

$$
\begin{equation*}
L_{R ; L}=\frac{1}{4} @_{x R ; L}\left(Q_{Q} \quad V Q_{R}\right)_{R ; L} \tag{15}
\end{equation*}
$$

( $v$ is the velocity of the excitations) and the equal-tim e com $m$ utation relations

$$
\begin{equation*}
[\mathrm{R} ; \mathrm{L}(\mathrm{t} ; \mathrm{x}) ; \mathrm{R} ; \mathrm{I}(\mathrm{t} ; \mathrm{y})]=\quad \mathrm{i} \operatorname{sgn}(\mathrm{x} \quad \mathrm{y}): \tag{16}
\end{equation*}
$$

Left and right $m$ oving electron operators can be written as $R_{R ; L}(x ; t)=: e^{i_{R ; L}(x, t)}:$, which can be show $n$ to satisfy the correct antioom $m$ utation relations [12]. T he electron density is given by $R ; L=@_{x R ; L}$, and the $H$ am iltonian is

$$
\begin{equation*}
H_{R ; L}=\frac{V}{4}^{Z} d x \underset{R ; L}{2}: \tag{17}
\end{equation*}
$$

C onsider three edge branches as depicted in Fig. 18, labelled by i=1;2;3. W e can generalize the description above to include severalbranches, writing the follow ing Lagrangian density:

$$
\begin{equation*}
L=\frac{1}{4}{\underset{i ; j}{ }\left[\mathbb{K}_{i j} @_{t}{ }_{i} @_{\mathrm{x}} \quad j \quad V_{i j} \varrho_{\mathrm{x}} \quad{ }_{i} \varrho_{\mathrm{x}} \quad j\right] ;}^{j} \tag{18}
\end{equation*}
$$

where the $m$ atrices $K$ and $V$ contain, respectively, inform ation on the direction of propagation (chirality) ofeach branch, and interactions between the branches (including a diagonal term containing the velocities). For this analysis let us assum e two $R$ branches (1 and 3) and one L branch (2), such that

$$
K=\begin{array}{cccc}
{ }^{0} & 1 & 0 & 0^{1}  \tag{19}\\
B_{B}^{B} & & & C_{i}^{C} \\
B_{0} & 0 & 1 & 0 \underset{A}{C} \\
0 & 0 & 1
\end{array}:
$$

E lectron operators can be w ritten as

$$
\begin{align*}
& L / e^{i^{P}}{ }_{i^{I_{i} i}}  \tag{20}\\
& I_{i}={ }_{j}^{X} K_{i j} L_{j} ; \tag{21}
\end{align*}
$$

where the $L_{i}$ 's are integers satisfying ${ }^{P}{ }_{i} L_{i}=1$. The Lagrangian in (18) is not the $m$ ost general one. W e left out four ferm ion term s that cannot be written as the product of two densities. W e know that it is the interactions between the densities that are responsible for changing the Ferm iedge singularity, and here we will concentrate on this particulare ect of interactions. W e have also assum ed a local interaction in the densities. H ow ever, the long range interaction can be easily included by allow ing $\mathrm{V}_{\mathrm{ij}}$ to have m om entum dependence. In
 where $k / \ln k$ is the Fourier transform ation of the $1=r$ C oulom b interaction and $k ; i$ the Fourier com ponent of the density of the $i^{\text {th }}$ branch. We see at long distances the most im portant interaction term is the one that involves only the totalcharge density ${ }^{P} \quad{ }_{i}$. This contribution is
which, when sum $m$ ed to the velocity term $s$, gives the totalV $m$ atrix

Here, for sim plicity, we have assum ed that is a large constant independent ofm om entum . $T$ his w illbe the case if the C oulom b interaction is screened at a long distance (e.g. by gates nearby). W e w ill focus prim arily in the case where v's, i.e., strongly coupled branches.

A lso, if the system has particlehole sym $m$ etry, then $v_{1}=V_{3}$. We start by rew riting the Lagrangian (18) in term $s$ of new elds $\sim_{i}={ }^{P}{ }_{j} U_{i j} \quad j$ that sim ultaneously diagonalize $K$ and $V$. Furtherm ore, we would like to keep, for convenience,

$$
\begin{equation*}
K=\left(U^{T}\right)^{1} K U^{1}=K \tag{24}
\end{equation*}
$$

so that the commutation relations of the ${ }^{\sim}$ 's are the same as the ones for the 's. The transform ation $m$ atrix $U$ for $\quad v^{\prime} S$ is

Them ode in the rst line of $U, \sim_{1}=1+2+3$, is sim ply the total charge density $m$ ode (equivalently, $\sim_{1}=1+2+3$, as $=Q_{x}$ ). W hat we show next is that, once we add to the Lagrangian 18) electron scattering term s due to the presence of im purities, this total charge m ode is left unperturbed, and the other two will localize.

The scattering term s between electron operators in the three edges that can be added to the Lagrangian are bosonic couplings w th zero charge. These can be written as $\mathrm{T}_{\mathrm{L}}=$ $e^{i^{P}}{ }_{i}{ }^{I_{i} i}=e^{i^{P}}{ }_{i j}{ }^{L_{i} K_{i j}}{ }^{j}$, where now the $L_{i}$ 's are integers satisfying ${ }^{P}{ }_{i} L_{i}=0$ ( $T_{L}$ is bosonic and neutral). In term $s$ of the rotated elds ${ }^{\sim}{ }^{\prime} S, T_{L}=e^{{ }^{P}}{ }_{i} I_{i} \tilde{N}_{i}$, where $I_{i}={ }^{P}{ }_{j} I_{j} U_{j i}{ }^{1}$. Let us focus on the $m$ ost relevant $T_{L}$ 's; the naive $R G$ dim ension can be obtained from the $T_{L}$ correlations

$$
\begin{align*}
& h T_{L}^{y}(t=0 ; x) T_{L}(t=0 ; x=0) i / e^{P} i_{i ; j} \tilde{i}_{1} \mathcal{I}_{j} \mathcal{h}_{i}(t=0 ; x) \sim_{j}(t=0 ; x=0) i  \tag{26}\\
& / x^{\mathrm{P}} \mathrm{i}^{\mathrm{L}_{1}^{2}}=\mathrm{x}^{\mathrm{L}} \text {; }
\end{align*}
$$

W riting L in term sof the L's we obtain:

$$
\begin{align*}
\mathrm{L} & ={ }^{X} \mathbb{I}_{i}^{2}=I^{T} I  \tag{27}\\
& =I^{T} U^{1}\left(U^{1}\right)^{T} I \\
& =L^{T} K U^{1}\left(U^{1}\right)^{T} K L
\end{align*}
$$

$$
\begin{aligned}
& =L^{\mathrm{T}} U^{\mathrm{T}}\left(U^{\mathrm{T}}\right)^{1} K U^{1}\left(U^{1}\right)^{\mathrm{T}} K U^{1} U L \\
& =L^{\mathrm{T}} U^{\mathrm{T}} K^{2} U L \\
& =L^{\mathrm{T}}\left(U^{\mathrm{T}} U\right) L ;
\end{aligned}
$$

where we used $K^{2}=K{ }^{2}=I$. It is easy to show that the minim um $L, w$ ith ${ }^{P}{ }_{i} L_{i}=0$, are given by:
which correspond to $T_{L}$ operators that transfer charges between the center branch ( $L$ ) to the two side branches $(\mathbb{R})$. In term s of the $\mathbb{T}^{\prime} \mathrm{s}$, we have:
$T$ he $H$ am iltonian density $w$ ith these $m$ ost relevant $T_{\mathrm{L}}$ term s added is

$$
\begin{equation*}
\mathrm{H}=\mathrm{H}_{0}+\mathrm{H}_{\mathrm{T}} \tag{30}
\end{equation*}
$$

where

$$
\begin{equation*}
H_{0}=\frac{W_{1}}{4}\left(@_{x} \tilde{x}_{1}\right)^{2}+\frac{V_{2}}{4}\left(@_{x} \tilde{2}_{2}\right)^{2}+\frac{W_{3}}{4}\left(@_{x} \tilde{3}_{3}\right)^{2} \tag{3}
\end{equation*}
$$

and

The describe the random tunneling coupling due to impurities, with correlations $h(x) \quad(y) i=\quad(x \quad y)$.

N otice that ~ $_{1}$ rem ains free, as the added tunneling term s do not depend on it. T his one com ponent (total charge, as $\sim_{1}=1_{1}+{ }_{2}+{ }_{3}$ ) behaves just like the one branch before the transition. The other tw o, we w illargue below, should be localized because of the im purities.

Let $\sim=\left(\begin{array}{cc}\sim_{2} & \sim_{3}\end{array}\right)={ }^{\mathrm{p}} \overline{2}$, which obey the com $m$ utation relations

$$
\begin{align*}
& { }^{h} \sim(t ; x) ; \sim(t ; y)^{i}=0  \tag{33}\\
& { }^{h} \sim(t ; x) ; \sim(t ; y)^{i}=i \operatorname{sgn}(x \quad y)
\end{align*}
$$

W e can identify $\sim=\frac{@_{x} \sim}{2}$ as the conjugatem om enta to $\sim$. W e can rew rite the H am iltonian for $\sim_{2}$ and $\sim_{3}$ in term sof $\sim$ :
where we assum e that $\psi_{2}$ vु $\quad v^{2}$. This is a m ore com plicated version of a Sine-G ordon (SG) H am iltonian density w ith position dependent coupling, as it involves self-interactions in both a eld and its con jugate $m$ om entum .

If we had only one of + or , we would have a Ham ittonian for a simple SG w ith position dependent coupling, which we could w rite as

$$
\begin{equation*}
H=\frac{V}{4}^{h}\left(2 y^{2}+\left(@_{x} \sim^{2}\right)^{i}+(x) e^{i^{\sim}}+H: c::\right. \tag{35}
\end{equation*}
$$

$W$ orking in units of $v=1$, and rescaling the elds as ${ }^{0}={ }^{\mathrm{P}} \overline{2} \sim$ and ${ }^{0}=\sim_{=}^{\mathrm{P}} \overline{2}$ (which keep the com $m$ utation relations unchanged), we have

$$
\begin{equation*}
H=\frac{1}{2}^{h} @+\left(@_{x}\right)^{2^{i}}+(x) e^{i g}+H: C: ; \tag{36}
\end{equation*}
$$

w ith $\mathrm{g}={ }^{\mathrm{P}} \overline{2}$. This problem, equivalent to a C oulom.b gasw ith position dependent chem ical potential, was studied in refs. [13 [14]. The im purity coupling is relevant for $\mathrm{g}<\mathrm{p} \frac{\mathrm{p}}{6}$ (in the constant coupling constant or chem ical potential Coulomb gas, the condition is $g<{ }^{\mathrm{P}} \overline{8}$ ). This is indeed our case, and therefore the presence of im purities localizes the other two branches of excitations represented by $\sim_{2}$ and $\sim_{3}$.

N otice that what we have done above is equivalent to understanding the RG ow $s$ in the planes + $=0$ and $=0$, and this implies are relevant in all directions around
$=0$ if $\mathrm{g}<\mathrm{P} \overline{6}$. TheRG ows to a strong xed point when both 0 . It is possible that this strong xed point is a localized state, m otivated by the ow when $=0$. The properties of this strong xed point will be the sub ject of further studies.

## VI.TUNNELLING INTORECONSTRUCTED EDGES

The form alism in the last section can be used to study the electron tunneling into the reconstructed edges. The electron propagator in tim e in general has a form

$$
<c^{y}(t) c(0)>/ \frac{1}{t^{L}}
$$

with L given in Eq. (27). But now the $\mathrm{L}_{\mathrm{i}}{ }^{\prime}$ S satisfy ${ }^{\mathrm{P}}{ }_{\mathrm{i}} \mathrm{L}_{\mathrm{i}}=1$. In the lim it $=\mathrm{V} \quad 1 \mathrm{U}$ is given by Eq. 25). The $m$ in $m$ um exponent is $\mathrm{L}=1$ (the Ferm i liquid value) for electrons described by $L=(1 ; 1 ; 1)$. This con guration corresponds to adding two electrons on the two side branches and rem oving one electron from the center branch. A dding a single electron to the side branch leads to a exponent $\mathrm{L}_{\mathrm{L}}=2$ and to the center branch $\mathrm{L}=3$.

Let us consider tunneling between two reconstructed edges. At very low tem peratures and low voltages, the electron with the con guration $L=(1 ; 1 ; 1)$ will dom inate the tunneling and leads to a linear I V curve [1b], since I/ V $\mathrm{V}^{2}{ }^{1}$ and $\mathrm{L}=1$. At higher voltages, depending on the sam ple geom etry, it $m$ ay be easier for an electron to just tunnel into the sidebranch ( $w$ th con guration $L=(1 ; 0 ; 0)$ ). In this case $I / V^{3}$ and $(d I=d V)_{V=0} /$ $\mathrm{T}^{2}$ 。

The above discussion also apply the reconstructed edges of Laughlin states of lling fraction $1=\mathrm{m}$. But now for the $\mathrm{L}=(1 ; 1 ; 1)$ electron the exponent $\mathrm{L}=\mathrm{m} . \mathrm{L}_{\mathrm{L}}=2 \mathrm{~m}$ for $L=(1 ; 0 ; 0)$ and $L=3 m$ for $L=(0 ; 1 ; 0)$. $W$ e see that in the lim it $=v \quad 1$ the $m$ inim um exponent in the electron propagator is not a ected by the edge reconstruction. $T$ his result is valid even when $m$ ore then one pair of edge branches are generated. This is because adding electrons of con guration $L=(1 ; 1 ; 1 ; 1 ;:: ; 1)$ just displace all the edge branches by the same am ount. Thus the electron of $L=(1 ; 1 ; 1 ; 1 ;:: ; 1)$ just couples to the total density ${ }^{P}$ i and do not couple to other neutralm odes. In the lim it $=v \quad 1$, the total density mode decouples from other neutral modes. This is the reason why the $\mathrm{L}=(1 ; 1 ; 1 ; 1 ;:: ; 1)$ electron alw ays have the exponent ${ }_{\mathrm{L}}=\mathrm{m} . \mathrm{W}$ e would like to stress that the above result is valid only at low energies (energies below the sm allest Ferm ienergy
of generated edge branches). The high energy behavior of the electron propagator is not clear. In that case it is probably better to view the edge region as a com pressible gas.

For tunneling between two reconstructed FQH edges, we expect I / V ${ }^{2 \mathrm{~m}}{ }^{1}$ and $(d I=d V)_{V=0} / T^{2 m}$ at low voltages and low tem peratures. This is consistent w ith a reœent experim ent on tunneling between (sm ooth) edges of $1=3 \mathrm{FQ} \mathrm{H}$ states. 16]

## V II. C O N C LU SIO N

In this paper we studied the electronic density of $Q$ uantum $H$ all Liquids, focusing on short length scales that are com parable w the the $m$ agnetic length. We found that sharp electronic occupation densities, corresponding to a $Z_{F}=1$ Ferm iL iquid, is possible because of the chiral nature of the system. T his sharp distribution is stable against variations in the con ning potential up to a certain point, beyond which it undergoes a transition and electrons start to separate from the bulk and deposit a distance 2 l aw ay. The transition is show $n$ to be qualitatively described w ithin the $H$ artree $F$ ock approxim ation. T he separation generates a pair ofbranches of edge states that $m$ ove in opposite directions.

W ew ould like to rem ark that the separated electrons do not form any fractionalquantum H all state. This is because the separation between the Ferm i edges is always of order $m$ agnetic length for realistic potentials. In this case $1=3,1=5, \ldots$ states are all described by Luttinger liquid and are indistinguishable.

W e also present results for Q uantum D ots, where we predict that this e ect of edge separation can be related to an expansion ofthe dot, which could be experim entally observed.

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## FIGURECAPTIONS

Figure 1. P ossible singularities for the $m$ om entum occupation distribution of a $=1$ state: (a) $Z_{F}=1$ Ferm iLiquid singularity, (b) $Z_{F}<1$ FermiLiquid singularity, and Luttinger Liquid singularity.

Figure 2. M om entum occupation distribution after reconstruction, w ith three singularities. The addition oftw o singularities corresp ond to the addition oftw o branches of opposite m oving edge excitations.

Figure 3. Cylindrical geom etry, equivalent to a strip of length $L$ and periodic boundary conditions, where it is convenient to use the Landau G auge. The QH Liquid (shaded area) lies on the surface of the cylinder, betw een its left and right edges at L and R .

Figure 4. The $=1$ droplet is divide into $\backslash$ bulk", where all the states are fully occupied, and \edge", in which states can be partially occupied. The division allow s one to focus the com putations solely on the \edge" electrons, w ith the \bulk" sim ply contributing to the one particle dispersion. This sort ofdivision is not unique, as one can adjust the position of the boundary betw een the two regions; this boundary can be m oved as long as the sites on the ledge" side of it are all fully occupied.

Figure 5. Sm oothened background charge density, which over a w idth w drops from its bulk value to zero. Such density can be written as the supenposition of a shanp density pro le tp a dipole term, which is used to tune the con ning potential as function of $w$.

Figure 6. Energy eigenstates obtained as function of the totalm om entum $K$ of the edge electrons for values of w ranging from 0 to 7 g. N otioe that the ground state for this range has $=K=45$, the $m$ inim um $m$ om entum con guration for 10 electrons (the 20 sites used in
the calculation are assigned k values from 0 to 19). A lso, notioe that the energy levels of states of higher K are pulled down as w increases.

Figure 7. For w 8 the ground state con guration is no longer the shanp edge distribution. The transition occurs near $w=8 l_{B}$, and for $w=9 l_{b}$ is already fully developed, w ith the ground state m om entum m oved to $\mathrm{K}=60$.

Figure 8. O ccupation num bers for the ground state past the transition, for $w=9$ and 10 l . N otice how a hum $p$ of density $m$ oves aw ay from the $m$ ain body of $Q H$ uid. This density pro le (which goes from its bulk value to zero by rst decreasing, then increasing, and nally decreasing again) is the signature of the existence of now three singularities, and thus three branches of edge excitations.

Figure 9. The e ective single particle potential calculated within the H artree Fock approxim ation for di erent widths $w$, decreasing from $0 l_{B}$ to $15 l_{B}$ in steps of $1 l_{B}$. Notioe that starting at w 11 , the condition for stability of a sharp edge is violated, as there are locations w ith sm aller e ective potential than the one at the edge of the sharp occupation density.

Figure 10. Energy levels and occupation num bers for $w=10 l_{B}$ calculated $w$ thin the H artree Fock approxim ation (the hoping or o -diagonal elem ents were suppressed).

Figure 11. O ccupation num ber of the angular $m$ om entum states as a function of 0 for $\mathrm{N}_{\mathrm{p}}=60$, calculated w thin the H artree $F$ ock approxim ation. The occupied orbits are represented in black, and the unoccupied ones are shown in white.

Figure 12.0 ccupation num ber of the angular $m$ om entum states as a function of $N_{p}$ for $0=6: 25 \quad 10^{2}$, calculated w ithin the H artree Fock approxim ation.

Figure 13. O ccupation num ber of the angular $m$ om entum states as a function of 0 for $N_{p}=60$, calculated $w$ ithin the $H$ artree approxim ation.

Figure 14. M inim um o necessary to keep an $\mathrm{N}_{\mathrm{p}}$-particle droplet com pacted, calculated using the H artree (a) and H artree Fock (b) approxim ation. The solid line is the best curve t consistent w ith an electrostatic (H artree) argum ent.

Figure 15. Dependence on the $m$ agnetic eld $B$ of the energy cost to add one $m$ ore particle, , to an island with 35 (lowest curve), 36, 37 and 38 (highest curve) electrons. The \saw tooth" corresponds to $1 \ll 2$, where electrons are spin ipped and taken from the center to the edge as the $m$ agnetic eld is increased. The \dislocations" near B 3T correspond to the transition between com pacted and separated dots. T he region in betw een (B) $2: 5$ to 3 T ) is the w indow forwhich the dot is a com pact $=1$ droplet. These results were obtained for the parabolic con ning potential of the sam ple studied in Ref. 7], w ith $0=0: 376 B^{3=2}$ ( $B$ in Tesla).
$F$ igure 16. Radius of the $Q H$ droplet for (a) $x e d N_{p}$ and varying 0 , and (b) xed 0 and varying $N_{p}$. O ne can vary oby changing the strength of the con ning potential, or by changing the $m$ agnetic eld. For the parabolic con ning potential of the sam ple studied in Ref. [7], the param eter $0=0: 376 B^{3=2}$ ( $B$ in Tesla).

Figure 17. M om entum occupation distribution after reconstruction, if calculated only within the $H$ artree Fock approxim ation. T he addition of two singularities correspond to the addition of tw o branches of opposite $m$ oving edge excitations.

Figure 18. Three branches of edge excitations, tw o right-m oving (1 and 3, on the sides) and one left-m oving ( 2, in the center).

